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SN54LVT16245B, SN74LVT16245B 3.3-V ABT 16-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

SCBS715E-FEBRUARY 2000-REVISED NOVEMBER 2006

FEATURES

- Member of the Texas Instruments Widebus™ Family
- State-of-the-Art Advanced BiCMOS
 Technology (ABT) Design for 3.3-V Operation and Low Static-Power Dissipation
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})
- Support Unregulated Battery Operation Down to 2.7 V
- Typical V_{OLP} (Output Ground Bounce) <0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- I_{off} and Power-Up 3-State Support Hot Insertion
- Distributed V_{CC} and GND Pins Minimize High-Speed Switching Noise
- Flow-Through Architecture Optimizes PCB Layout
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

SN54LVT16245B...WD PACKAGE SN74LVT16245B...DGG, DGV, OR DL PACKAGE (TOP VIEW)

		1 1		
1DIR [1	\cup	48] 1 <u>OE</u>
1B1 [2		47] 1A1
1B2 [3		46] 1A2
GND [4		45	GND
1B3 [5		44] 1A3
1B4 [6		43	1A4
V _{CC}	7		42	V_{CC}
1B5 [8		41] 1A5
1B6 [9		40] 1A6
GND [10		39	GND
1B7 [11		38] 1A7
1B8 [12		37] 1A8
2B1 [13		36] 2A1
2B2 [14		35	2A2
GND [15		34	GND
2B3 [16		33] 2A3
2B4 [17		32	2A4
v _{cc} [18		31] v _{cc}
2B5 [19		30] 2A5
2B6 [20		29	2A6
GND [21		28	GND
2B7 [22		27	2A7
2B8 [23		26	2A8
2DIR [24		25	2 0E
				l

DESCRIPTION/ORDERING INFORMATION

ORDERING INFORMATION

T _A	PACKAG	E ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	FBGA – GRD	Reel of 1000	SN74LVT16245BGRDR	VD245B
	FBGA – ZRD (Pb-free)	Reel of 1000	SN74LVT16245BZRDR	VD240B
		Tube of 25	SN74LVT16245BDL	
	SSOP – DL	Tube of 25	SN74LVT16245BDLG4	LVT16245B
	330F - DL	Reel of 1000	SN74LVT16245BDLR	LV110243B
-40°C to 85°C		Reel of 1000	74LVT16245BDLRG4	
-40 C to 65 C	TSSOP – DGG	Reel of 2000	SN74LVT16245BDGGR	LVT16245B
	1330F - DGG	Reel of 2000	74LVT16245BDGGRE4	LV110243D
	TVSOP – DGV	Reel of 2000	SN74LVT16245BDGVR	VD245B
	TVSOF - DGV	Reel of 2000	74LVT16245BDGVRE4	VD243B
	VFBGA – GQL	Reel of 1000	SN74LVT16245BGQLR	VD245B
	VFBGA – ZQL (Pb-free)		SN74LVT16245BZQLR	VD240D
–55°C to 125°C	CFP – WD	Tube	SNJ54LVT16245BWD	SNJ54LVT16245BWD

⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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DESCRIPTION/ORDERING INFORMATION (CONTINUED)

The 'LVT16245B devices are 16-bit (dual-octal) noninverting 3-state transceivers designed for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

These devices are designed for asynchronous communication between two data buses. The logic levels of the direction-control (DIR) input and the output-enable (\overline{OE}) input activate either the B-port outputs or the A-port outputs or place both output ports into the high-impedance mode. The device transmits data from the A bus to the B bus when the B-port outputs are activated, and from the B bus to the A bus when the A-port outputs are activated. The input circuitry on both A and B ports is always active and must have a logic HIGH or LOW level applied to prevent excess I_{CC} and I_{CCZ} .

When V_{CC} is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for hot-insertion applications using $I_{\rm off}$ and power-up 3-state. The $I_{\rm off}$ circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

GQL OR ZQL PACKAGE (TOP VIEW)

	_	1	2	3	4	5	6	
Δ	$\overline{}$		()	()		()		1
В		Ó	()	()	()	()	()	ı
С		()	()	()	()	()	()	ı
D		()	()	()	()	()	()	ı
Е		()	()			()	()	ı
F		()	()			()	()	ı
G		()	()	()	()	()	()	ı
н		()	()	()	()	()	()	ı
J		()	()	()	()	()	()	ı
K		()	()	()	()	()	()	J

TERMINAL ASSIGNMENTS⁽¹⁾ (56-Ball GQL/ZQL Package)

	1	2	3	4	5	6
Α	1DIR	NC	NC	NC	NC	1 OE
В	1B2	1B1	GND	GND	1A1	1A2
С	1B4	1B3	V _{CC}	V _{CC}	1A3	1A4
D	1B6	1B5	GND	GND	1A5	1A6
E	1B8	1B7			1A7	1A8
F	2B1	2B2			2A2	2A1
G	2B3	2B4	GND	GND	2A4	2A3
Н	2B5	2B6	V _{CC}	V _{CC}	2A6	2A5
J	2B7	2B8	GND	GND	2A8	2A7
K	2DIR	NC	NC	NC	NC	2 OE

(1) NC - No internal connection

GRD OR ZRD PACKAGE (TOP VIEW)

		1	2	3	4	5	6	
Α	\bigcap	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	
В		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	
С		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	
D		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	
E		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	
F		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	
G		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	
Н		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	
J		\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	\bigcirc	
	/							_

TERMINAL ASSIGNMENTS⁽¹⁾ (54-Ball GRD/ZRD Package)

	1	2	3	4	5	6
Α	1B1	NC	1DIR	1 OE	NC	1A1
В	1B3	1B2	NC	NC	1A2	1A3
С	1B5	1B4	V _{CC}	V _{CC}	1A4	1A5
D	1B7	1B6	GND	GND	1A6	1A7
E	2B1	1B8	GND	GND	1A8	2A1
F	2B3	2B2	GND	GND	2A2	2A3
G	2B5	2B4	V _{CC}	V _{CC}	2A4	2A5
Н	2B7	2B6	NC	NC	2A6	2A7
J	2B8	NC	2DIR	2 OE	NC	2A8

(1) NC - No internal connection

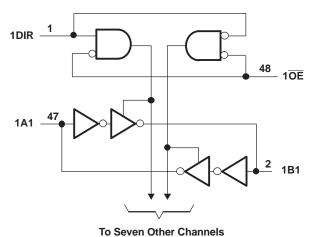


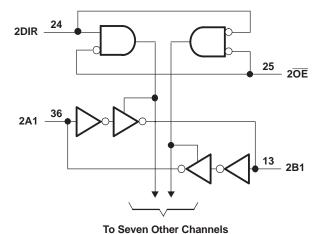
FUNCTION TABLE⁽¹⁾ (each 8-bit section)

CONTRO	L INPUTS	OUTPUT C	IRCUITS	OPERATION
ŌĒ	ŌĒ DIR		B PORT	OPERATION
L	L	Enabled	Hi-Z	B data to A bus
L	Н	Hi-Z	Enabled	A data to B bus
Н	Χ	Hi-Z	Hi-Z	Isolation

(1) Input circuits of the data I/Os always are active.

LOGIC DIAGRAM (POSITIVE LOGIC)





3

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Absolute Maximum Ratings(1)

over recommended operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	4.6	V
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Voltage range applied to any output in the high-impedance	e or power-off state ⁽²⁾	-0.5	7	V
Vo	Voltage range applied to any output in the high state (2)	-0.5	V _{CC} + 0.5	V	
	Current into any autout in the law state	SN54LVT16245B		96	mA
I _O	Current into any output in the low state	SN74LVT16245B		128	MA
	Comment into any output in the bink state (3)	SN54LVT16245B		48	A
I _O	Current into any output in the high state ⁽³⁾	SN74LVT16245B		64	mA
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
		DGG package		70	
		DGV package		58	
θ_{JA}	Package thermal impedance (4)	DL package		63	°C/W
		GQL/ZQL package		42	
			36		
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

 ⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
 (3) This current flows only when the output is in the high state and V_O > V_{CC}.
 (4) The package thermal impedance is calculated in accordance with JESD 51-7.



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Recommended Operating Conditions⁽¹⁾

			SN54LVT162	245B ⁽²⁾	SN74LVT	16245B	UNIT
			MIN	MAX	MIN	MAX	UNII
V _{CC}	Supply voltage		2.7	3.6	2.7	3.6	V
V_{IH}	High-level input voltage		2		2		V
V_{IL}	Low-level input voltage			0.8		0.8	V
V_{I}	Input voltage			5.5		5.5	V
I _{OH}	High-level output current			-24		-32	mA
I _{OL}	Low-level output current			48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate		200		200		μs/V
T_A	Operating free-air temperature	·	– 55	125	-40	85	°C

⁽¹⁾ All unused or undriven (floating) inputs (I/Os) of the device must be held at logic HIGH or LOW (preferably V_{CC} or GND) to ensure proper device operation and minimize power. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

⁽²⁾ Product preview

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Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEOT	CONDITIONS	SN54L	-VT16245B ⁽¹⁾	SN74L	VT16245B	
P	AKAMETEK	IESI (CONDITIONS	MIN	TYP ⁽²⁾ MAX	MIN	TYP ⁽²⁾ MAX	UNIT
V_{IK}		$V_{CC} = 2.7 \text{ V},$	$I_I = -18 \text{ mA}$		-1.2		-1.2	V
		$V_{CC} = 2.7 \text{ to } 3.6 \text{ V},$	$I_{OH} = -100 \ \mu A$	V _{CC} - 0.2		V _{CC} - 0.2		
\/		$V_{CC} = 2.7 \text{ V},$	$I_{OH} = -8 \text{ mA}$	2.4		2.4		V
V _{OH}		V 2.V	I _{OH} = -24 mA	2				V
		$V_{CC} = 3 V$	$I_{OH} = -32 \text{ mA}$			2		
		V 0.7.V	I _{OL} = 100 μA		0.2		0.2	
		$V_{CC} = 2.7 \text{ V}$	I _{OL} = 24 mA		0.5		0.5	
١/			I _{OL} = 16 mA		0.4		0.4	V
V _{OL}		V 2.V	I _{OL} = 32 mA		0.5		0.5	V
		$V_{CC} = 3 V$	I _{OL} = 48 mA		0.55			
			I _{OL} = 64 mA				0.55	
	Control	$V_{CC} = 3.6 \text{ V},$	$V_I = V_{CC}$ or GND		±1		±1	
	inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V _I = 5.5 V		10		10	
I			$V_{CC} = 3.6 \text{ V}$ $V_{I} = 5.5 \text{ V}$ $V_{I} = V_{CC}$		20		20	μΑ
	A or B port ⁽³⁾	$V_{CC} = 3.6 \text{ V}$			5		1	
	port		$V_I = 0$		-5		- 5	
I _{off}		V _{CC} = 0,	V_I or $V_O = 0$ to 4.5 V				±100	μΑ
I _{OZP}	U	$\frac{V_{CC}}{OE} = 0$ to 1.5 V, V_{O}	= 0.5 V to 3 V,		±100 ⁽⁴⁾		±100	μΑ
I _{OZP}	D	$\frac{V_{CC}}{OE}$ = 1.5 V to 0, V_{O}	= 0.5 V to 3 V,		±100 ⁽⁴⁾		±100	μΑ
		V _{CC} = 3.6 V,	Outputs high		0.19		0.19	
I_{CC}		$I_{O} = 0$	Outputs low		5		5	
		$V_I = V_{CC}$ or GND	Outputs disabled	0.			0.19	
Δl _{CC}	· (5)	V_{CC} = 3 V to 3.6 V, One input at V_{CC} – 0.6 V Other inputs at V_{CC} or GND			0.2		0.2	mA
Ci		V _I = 3 V or 0			4			pF
C _{io}		$V_0 = 3 \text{ V or } 0$			10		10	pF

Product preview
 All typical values are at V_{CC} = 3.3 V, T_A = 25°C.
 Unused pins at V_{CC} or GND.
 On products compliant to MIL-PRF-38535, this parameter is not production tested.
 This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.

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Switching Characteristics

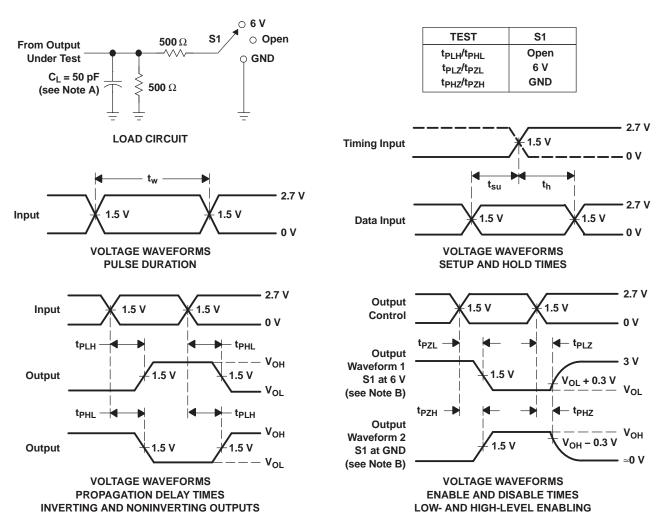
over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

			SN	SN54LVT16245B ⁽¹⁾				SN74LVT16245B				
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CC} = 3.3 V \pm 0.3 V		V _{CC} = 2.7 V		V_{CC} = 3.3 V \pm 0.3 V			V _{CC} = 2.7 V		UNIT
			MIN	MAX	MIN	MAX	MIN	TYP ⁽²⁾	MAX	MIN	MAX	
t _{PLH}	A or B	B or A	0.5	4.5		4.6	1.5	2.3	3.3		3.7	20
t _{PHL}	AUIB	BUIA	0.5	4.4		3.9	1.3	2.1	3.3		3.5	ns
t _{PZH}	ŌĒ	A or B	0.5	6.5		6.6	1.5	2.8	4.5		5.3	ns
t _{PZL}	OL	AOIB	0.5	5.4		6.2	1.6	2.9	4.6		5.2	113
t _{PHZ}	ŌĒ	A or B	1	6.8		7	2.3	3.7	5.1		5.5	nc
t _{PLZ}	OE	AUB	1	6.2		6.3	2.2	3.5	5.1		5.4	ns
t _{sk(LH)}									0.5			ns
t _{sk(HL)}									0.5			115

⁽¹⁾ Product preview (2) All typical values are at V_{CC} = 3.3 V, T_A = 25°C.



PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{O} = 50 Ω , $t_{f} \leq$ 2.5 ns, $t_{f} \leq$ 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





11-Apr-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
74LVT16245BDGGRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT16245B	Samples
74LVT16245BDGGRG4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT16245B	Samples
74LVT16245BDGVRE4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VD245B	Samples
74LVT16245BDGVRG4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VD245B	Samples
74LVT16245BDLRG4	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT16245B	Samples
SN74LVT16245BDGGR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT16245B	Samples
SN74LVT16245BDGVR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VD245B	Samples
SN74LVT16245BDL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT16245B	Samples
SN74LVT16245BDLG4	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT16245B	Samples
SN74LVT16245BDLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVT16245B	Samples
SN74LVT16245BGQLR	OBSOLETI	E BGA MICROSTAR JUNIOR	GQL	56		TBD	Call TI	Call TI	-40 to 85	VD245B	
SN74LVT16245BGRDR	OBSOLETI	E BGA MICROSTAR JUNIOR	GRD	54		TBD	Call TI	Call TI	-40 to 85	VD245B	
SN74LVT16245BZQLR	ACTIVE	BGA MICROSTAR JUNIOR	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	VD245B	Samples
SN74LVT16245BZRDR	ACTIVE	BGA MICROSTAR JUNIOR	ZRD	54	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	VD245B	Samples

⁽¹⁾ The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs.



PACKAGE OPTION ADDENDUM

11-Apr-2013

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVT16245BDGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	15.8	1.8	12.0	24.0	Q1
SN74LVT16245BDGVR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1
SN74LVT16245BDLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1
SN74LVT16245BZQLR	BGA MI CROSTA R JUNI OR	ZQL	56	1000	330.0	16.4	4.8	7.3	1.5	8.0	16.0	Q1
SN74LVT16245BZRDR	BGA MI CROSTA R JUNI OR	ZRD	54	1000	330.0	16.4	5.8	8.3	1.55	8.0	16.0	Q1

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*All dimensions are nominal

All differsions are nominal									
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)		
SN74LVT16245BDGGR	TSSOP	DGG	48	2000	367.0	367.0	45.0		
SN74LVT16245BDGVR	TVSOP	DGV	48	2000	367.0	367.0	38.0		
SN74LVT16245BDLR	SSOP	DL	48	1000	367.0	367.0	55.0		
SN74LVT16245BZQLR	BGA MICROSTAR JUNIOR	ZQL	56	1000	336.6	336.6	28.6		
SN74LVT16245BZRDR	BGA MICROSTAR JUNIOR	ZRD	54	1000	336.6	336.6	28.6		

ZQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

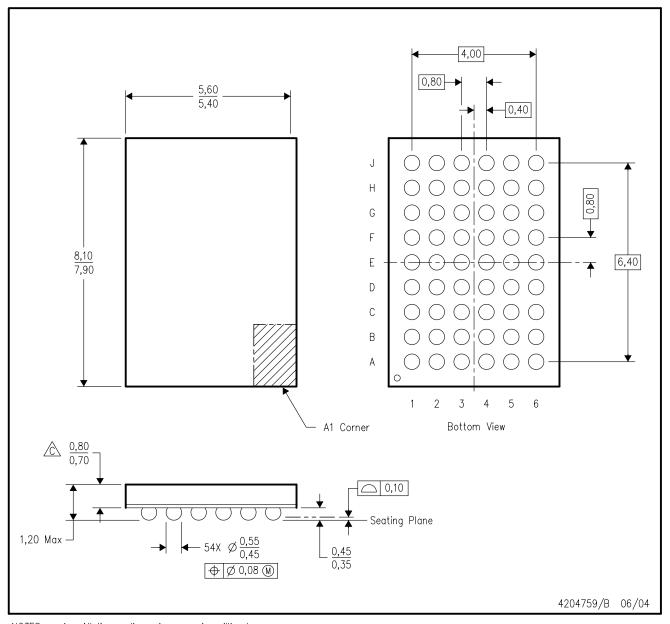
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is Pb-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).

MicroStar Junior is a trademark of Texas Instruments



GRD (R-PBGA-N54)

PLASTIC BALL GRID ARRAY



 $\hbox{NOTES:} \quad \hbox{A. All linear dimensions are in millimeters.}$

B. This drawing is subject to change without notice.

Falls within JEDEC MO-205 variation DD.

D. This package is tin-lead (SnPb). Refer to the 54 ZRD package (drawing 4204760) for lead-free.



ZRD (R-PBGA-N54)

PLASTIC BALL GRID ARRAY



 $\hbox{NOTES:} \quad \hbox{A. All linear dimensions are in millimeters.}$

- B. This drawing is subject to change without notice.
- Falls within JEDEC MO-205 variation DD.
- D. This package is lead-free. Refer to the 54 GRD package (drawing 4204759) for tin-lead (SnPb).



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

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GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-285 variation BA-2.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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